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(Rev. 10/02)	0 - 2005 U.S. DEPARTMENT OF COMME U.S. Patent and Trademark
OMB No. 0651-0027 (exp. 6/30/2005)	U.S. Patent and Trademark
Tab settings	407635
To the Honorable Commissioner of F 103	127635, une attached original documents or copy thereof.
Name of conveying party(ies):	Name and address of receiving party(ies)
Chung-Zen Chen	Name: Elite Semiconductor Memory Technolog
	Internal Address:
Additional name(s) of conveying party(ies) attached? Yes V	
3. Nature of conveyance:	
✓ Assignment Merger	
	Street Address: No. 23, Industry E. Rd IV,
	Science-Based Industrial Park
Other	
	City: Hsinchu 300 State: Zip:
Execution Date: 11/21/2005	Taiwan, R.O.C. Additional name(s) & address(es) attached? Yes
Application number(s) or patent number(s):	Additional hame(s) diadoress(cs) attached:
	plication, the execution date of the application is: 11/21/2
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A. Patent Application No.(s)	B. Patent No.(s)
Additional numbers	attached? Yes No
Name and address of party to whom correspondence	
concerning document should be mailed:	o. Total number of applications and patents involved.
Name: Joseph A. Powers	7. Total fee (37 CFR 3.41)\$_40.00
Internal Address	Enclosed
Internal Address:	
	Authorized to be abarreed to deposit assesset
	Authorized to be charged to deposit account
Street Address: Duane Morris LLP	Authorized to be charged to deposit account 8. Deposit account number:
Street Address: Duane Morris LLP	
Street Address: Duane Morris LLP 30 South 17th Street	8. Deposit account number:
	8. Deposit account number:
30 South 17th Street City: Philadelphia State: PA Zip: 19103 DO NOT US	8. Deposit account number:
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30 South 17th Street City: Philadelphia State: PA Zip: 19103 DO NOT US	8. Deposit account number: 04-1679
30 South 17th Street City: Philadelphia State: PA Zip: 19103 DO NOT US	8. Deposit account number: 04-1679

Mail documents to be recorded with required cover sheet information to:

ASSIGNMENT AND AGREEMENT

For value received, I, Chung-Zen Chen, hereby sell, assign and transfer to Elite Semiconductor Memory Technology Inc., with its principal place of business located at No. 23, Industry E. Rd IV, Science-Based Industrial Park, Hsinchu 300, Taiwan, Republic of China, and its successors, assigns and legal representatives, the entire right, title and interest, for the United States of America, in and to certain inventions related to METHOD AND APPARATUS FOR REDUCING STRESS IN WORD LINE DRIVER TRANSISTORS DURING ERASURE described in an application for Letters Patent of the United States and all the rights and privileges in said application and under any and all Letters Patent and any divisions, continuations, continuations-in-part, reexamination certificates, reissues, and extensions thereof that may be granted in the United States for said inventions; and I also concurrently hereby sell, assign and transfer to Elite Semiconductor Memory Technology Inc. the entire right, title and interest in and to said inventions for all countries foreign to the United States, including all rights of priority arising from the application aforesaid, and all the rights and privileges under any and all forms of protection, including Letters Patent, that may be granted in said countries foreign to the United States for said inventions.

I authorize Elite Semiconductor Memory Technology Inc. to make application for such protection in its own name and maintain such protection in any and all countries foreign to the United States, and to invoke and claim for any application for patent or other form of protection for said inventions, without further authorization from me, any and all benefits, including the right of priority provided by any and all treaties, conventions, or agreements.

I hereby consent that a copy of this assignment shall be deemed a full legal and formal equivalent of any document which may be required in any country in proof of the right of Elite Semiconductor Memory Technology Inc. to apply for patent or other form of protection for said inventions and to claim the aforesaid benefit of the right of priority.

I request that any and all patents for said inventions be issued to Elite Semiconductor Memory Technology Inc. in the United States and in all countries foreign to the United States, or to such nominees as Elite Semiconductor Memory Technology Inc. may designate.

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PATENT REEL: 017246 FRAME: 0529

I agree that, when requested, I shall, without charge to Elite Semiconductor Memory Technology Inc. but at its expense, sign all papers, and do all acts which may be necessary, desirable or convenient in connection with said applications, patents, or other forms of protection.

(Sole) Inventor

Dated: 11 - 21, 2115

Chung-Zen Chen
Chung-Zen Chen

Residence: 2F.-2, No. 50, Daxue Rd.

RECORDED: 11/21/2005

Hsinchu 300, Taiwan, Republic of China

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PATENT REEL: 017246 FRAME: 0530